## NSN 5962-01-119-6664

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| View Online at https://aerobasegroup.com/nsn/5962-01-119-6664   |
|---|
| Body Length:  |
| Between 0.745 inches and 0.755 inches   |
| Body Width:   |
| Between 0.245 inches and 0.252 inches   |
| Body Height:  |
| Between 0.115 inches and 0.125 inches   |
| Maximum Power Dissipation Rating:   |
| 333.0 milliwatts  |
| Operating Tempurature Range:  |
| +0.0/+75.0 degrees celsius  |
| Storage Tempurature Range:  |
| -65.0/+150.0 degrees celsius  |
| End Application:  |
| Ts-3852 v2g e/i fscm 80058  |
| Features Provided:  |
| Monolithic and bipolar and expandable and positive outputs and w/enable and 3-state output  |
| Inclosure Material:   |
| Plastic   |
| Inclosure Configuration:  |
| Dual-in-line  |
| Output Logic Form:  |
| Transistor-transistor logic   |
| Input Circuit Pattern:  |
| 6 input   |
| Terminal Surface Treatment:   |
| Solder  |
| Voltage Rating And Type Per Characteristic:   |
| -1.5 volts power source and 5.5 volts power source  |
| Time Rating Per Chacteristic:   |
| 65.00 nanoseconds propagation delay time, low to high level output and 65.00 nanoseconds propagation delay time, high to low level        |
| output  |
| Memory Device Type:   |
| Rom   |
| Test Data Document:   |
| 50621-021-0005 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; |
| excludes any specification, standard or other document that may be referenced in a basic governing drawing)                               |
| Terminal Type And Quantity:   |
| 16 printed circuit  |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |

Yes - demil/mli

Demilitarization:

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